**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 19 A



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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	19 A				
V <sub>R</sub>	15 V				
V <sub>F</sub> at I <sub>F</sub>	0.32 V				
I <sub>RM</sub> max.	522 mA at 100 °C				
T <sub>J</sub> max.	125 °C				
E <sub>AS</sub>	6.75 mJ				
Package	2L TO-220AC				
Circuit configuration	Single				

#### **FEATURES**

- 125 °C T<sub>J</sub> operation (V<sub>B</sub> < 5 V)</li>
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- · High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and gualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

The VS-19TQ015... Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES UNIT					
I <sub>F(AV)</sub>	Rectangular waveform	19	А			
V <sub>RRM</sub>		15	V			
I <sub>FSM</sub>	$t_p = 5 \ \mu s \ sine$	700	А			
V <sub>F</sub>	19 A <sub>pk</sub> , T <sub>J</sub> = 75 °C	0.32	V			
TJ	Range	-55 to +125	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-19TQ015-M3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	15	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	15	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_{C}$ = 80 °C,	19				
Maximum peak one cycle non-repetitive surge current	<b>1</b>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	700	A		
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	330			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L = 6 mH		6.75	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim		1.50	А		

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HALOGEN

FREE

UNITS

٧

mΑ

pF

nΗ

V/µs



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES			
	V <sub>FM</sub> <sup>(1)</sup>	19 A	T.I = 25 °C	0.36			
Maximum forward voltage drop		38 A	1j=25 C	0.46			
See fig. 1		19 A	T <sub>.1</sub> = 75 °C	0.32			
		38 A	1j=75 C	0.43			
	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 100 °C, V <sub>R</sub> = 12 V		465			
Maximum reverse leakage current		$T_{\rm J} = 100 \ ^{\circ}{\rm C}, \ V_{\rm R} = 5 \ {\rm V}$		285			
See fig. 2		T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	10.5			
		T <sub>J</sub> = 100 °C	$v_{\rm R} = naleu v_{\rm R}$	522			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	2000				
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 8.0					

Rated V<sub>R</sub>

dV/dt

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

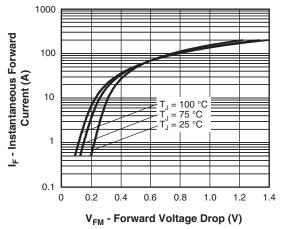
Maximum voltage rate of change

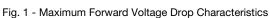
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction tempera	ture range	TJ		-55 to 125	°C	
Maximum storage temperat	ture range	T <sub>Stg</sub>		-55 to 150	°C	
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	1.50	°C / M	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub> Mounting surface, smooth and greased		0.50	°C/W	
Approximate weight				2	g	
				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque -	maximum			12 (10)	(lĎf · in)	
Marking device Case style 2L TO-220AC 19		19TC	015			



VS-19TQ015-M3

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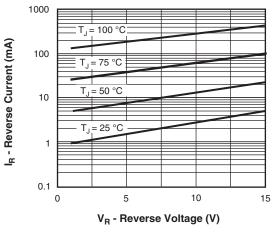


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

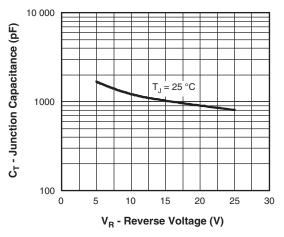


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

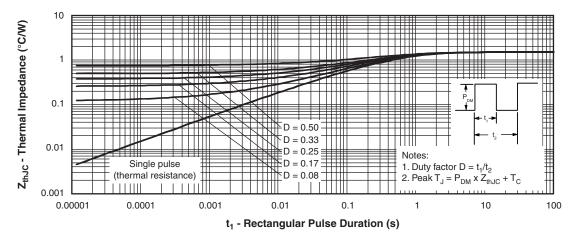
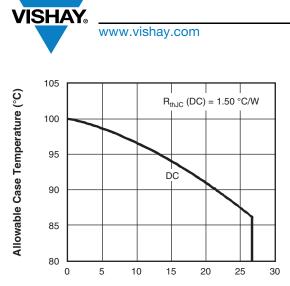


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

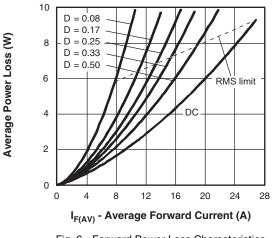


Fig. 6 - Forward Power Loss Characteristics

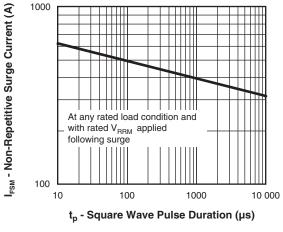
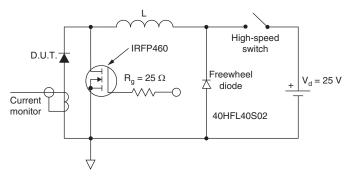


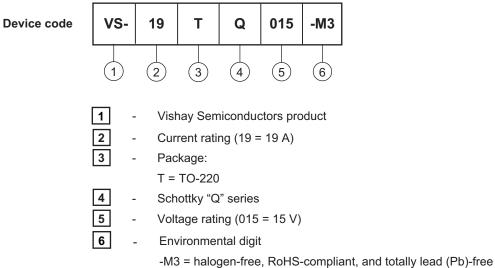
Fig. 7 - Maximum Non-Repetitive Surge Current







#### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-19TQ015-M3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96156</u>				
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?96005			



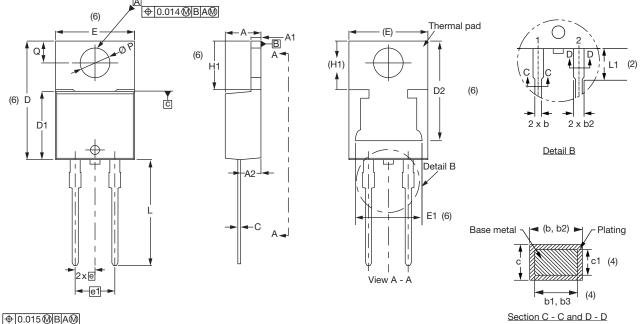
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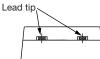


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# 2L TO-220AC

#### **DIMENSIONS** in millimeters and inches





SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	K. MIN. MAX.		NOTES	
А	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.50	2.92	0.098	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.35	0.585	0.604	3	
D1	8.38	9.02	0.330	0.355		

Conforms to JEDEC®	outline	TO-220AC
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SYMBOL	MILLIN	MILLIMETERS		INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
E	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØР	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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<sup>&</sup>lt;sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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